

<<基于硅技术24GHz汽车雷达的微波>>

图书基本信息

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内容概要

基于硅技术24GHz汽车雷达的微波电路介绍了设计、实现微波电路以及CMOS和SiGe双极技术的微波接收器电路特性。

基于硅技术24GHz汽车雷达的微波电路所介绍的电路设计适用于汽车工业应用技术，如车道变换辅助系统以及报警器等。

基于硅技术24GHz汽车雷达的微波电路适合相关专业研究生以及高年级本科生使用。

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